Description

The SX80N07NF uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with Hight EAS. This device is suitable for use as a Battery protectionor in other Switching application.

General Features

V_{DS} = 68V I_D =80A

$R_{DS(ON)}$ < 9.0mΩ @ V_{GS}=10V

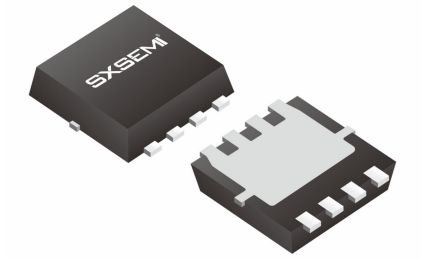
Application

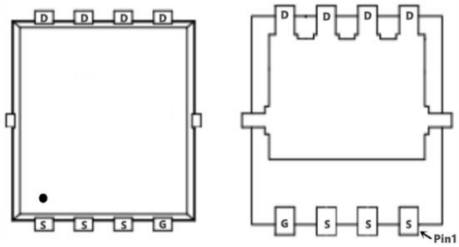
Battery protection

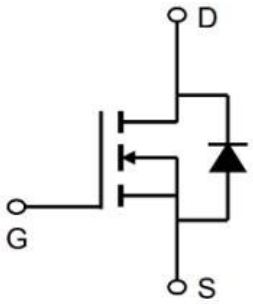
Load switch

Uninterruptible power supply

PDFN5*6-8L







Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Symbol	Parameter	Rating	Units
VDS	Drain-Source Voltage	68	V
VGS	Gate-Source Voltage	±20	V
I_D@T_C=25℃	Continuous Drain Current, V_{GS} @ 10V[1]	80	A
I_D@T_C=100℃	Continuous Drain Current, V_{GS} @ 10V[1]	52	A
IDM	Pulsed Drain Current[2]	320	A
EAS	Single Pulse Avalanche Energy[3]	110	mJ
IAS	Avalanche Current	22	A
P_D@T_C=25℃	Total Power Dissipation[4]	103	W
TSTG	Storage Temperature Range	-55 to 150	℃
T_J	Operating Junction Temperature Range	-55 to 150	℃
RθJA	Thermal Resistance Junction-ambient [1]	63	℃/W
RθJC	Thermal Resistance Junction-Case[1]	1.46	℃/W

Electrical Characteristics (T_J=25℃, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	V_{GS}=0V，I_D=250uA	68	72	---	V
△BVDSS/△TJ	BVDSS Temperature Coefficient	Reference to 25℃，I_D=1mA	---	0.023	---	V/℃
RDS(ON)	Static Drain-Source On-Resistance[2]	V_{GS}=10V，I_D=10A	---	7.5	9.0	mΩ
VGS(th)	Gate Threshold Voltage	V_{GS}=V_{DS}，I_D =250uA	2.0	3.0	4.0	V
△$V_{GS(th)}$	$V_{GS(th)}$ Temperature Coefficient		---	-4.2	---	mV/℃
IDSS	Drain-Source Leakage Current	V_{DS}=68V，V_{GS}=0V，T_J=25℃	---	---	1	uA
		V_{DS}=68V，V_{GS}=0V，T_J=55℃	---	---	5	
IGSS	Gate-Source Leakage Current	V_{GS}=±20V，V_{DS}=0V	---	---	±100	nA
Q_g	Total Gate Charge (4.5V)	VDS =30V, ID =30A, VGS =10V	---	35	---	nC
Qgs	Gate-Source Charge		---	11	---	
Qgd	Gate-Drain Charge		---	9	---	
Td(on)	Turn-On Delay Time	VDS =30V,ID =30A, RGEN =3Ω, V GS =10V	---	15	---	ns
T_r	Rise Time		---	90	---	
Td(off)	Turn-Off Delay Time		---	45	---	
T_f	Fall Time		---	30	---	
Ciss	Input Capacitance	V_{DS}=15V，V_{GS}=0V，f=1MHz	---	4060	---	pF
Coss	Output Capacitance		---	267	---	
Crss	Reverse Transfer Capacitance		---	250	---	
IS	Continuous Source Current[1,5]	V_G=V_D=0V，Force Current	---	---	80	A
ISM	Pulsed Source Current[2,5]		---	---	320	A
VSD	Diode Forward Voltage[2]	V GS =0V, I S =80A	---	---	1.2	V
trr	Reverse Recovery Time	T J =25℃ I F =20A,dI/dt=100A/μs	---	78	---	nS
Q_{rr}	Reverse Recovery Charge		---	51	---	nC

Note：

1、The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
2、The data tested by pulsed，pulse width .The EAS data shows Max. rating .
3、The test cond ≦ 300us duty cycle ≦ 2%, duty cycle ition is TJ =25℃, VDD =35V, VG =10V, R G =25Ω, L=0.5mH, IAS =21A
4、The power dissipation is limited by 175℃junction temperature
5、The data is theoretically the same as ID and IDM，in real applications，should be limited by total power dissipation.

Typical Characteristics

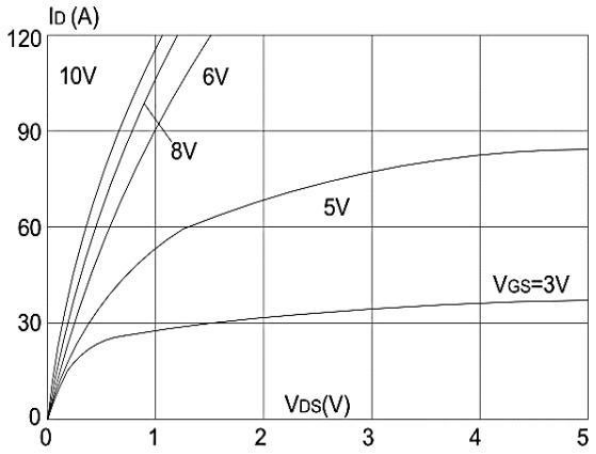


Figure1: Output Characteristics

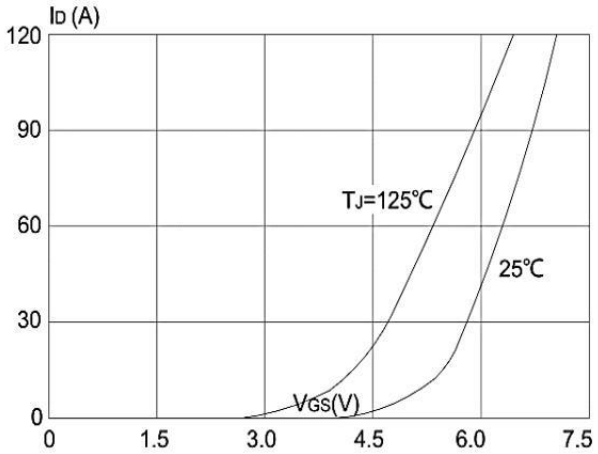


Figure 2: Typical Transfer Characteristics

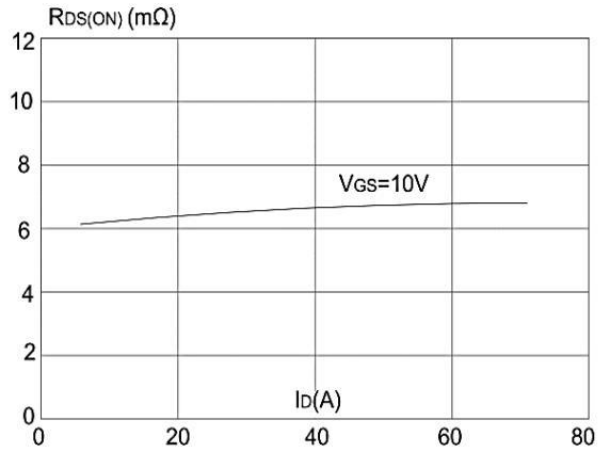


Figure 3:On-resistance vs. Drain Current

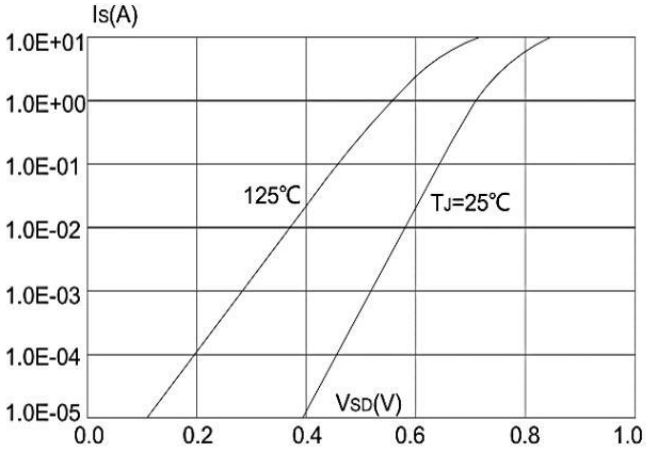


Figure 4: Body Diode Characteristics

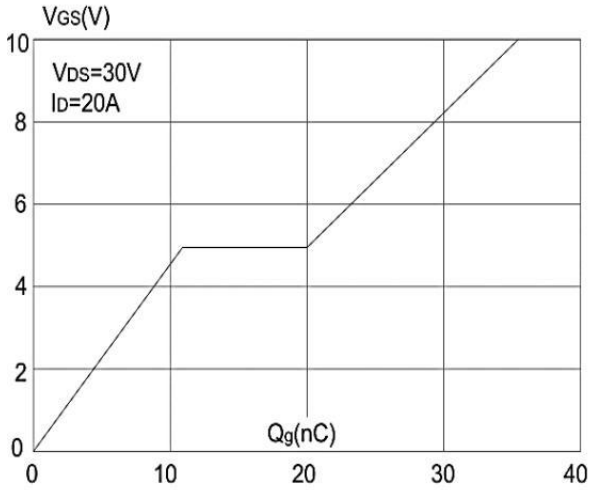


Figure 5: Gate Charge Characteristics

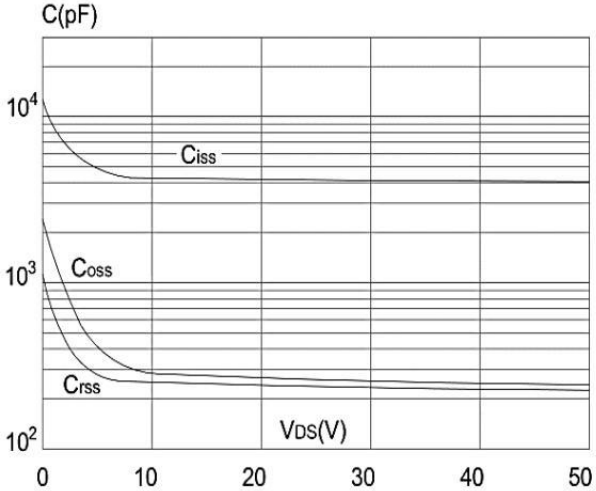


Figure 6: Capacitance Characteristics

Typical Characteristics

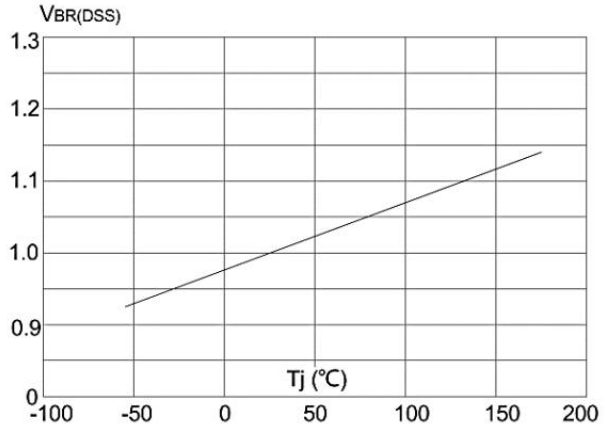


Figure 7: Normalized Breakdown Voltage vs Junction Temperature

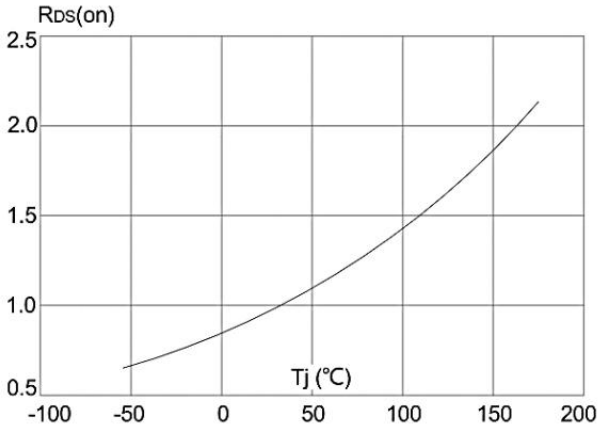


Figure 8: Normalized on Resistance vs. Junction Temperature

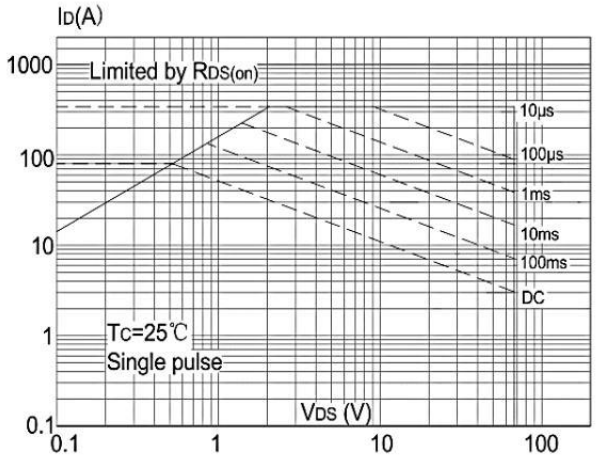


Figure 9: Maximum Safe Operating Area

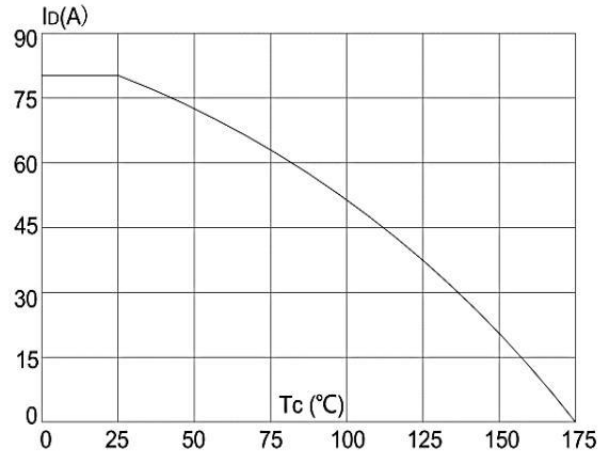


Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature

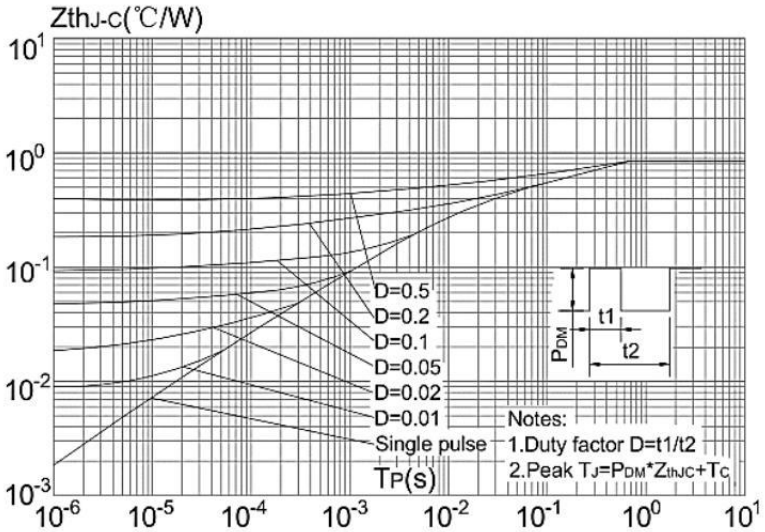
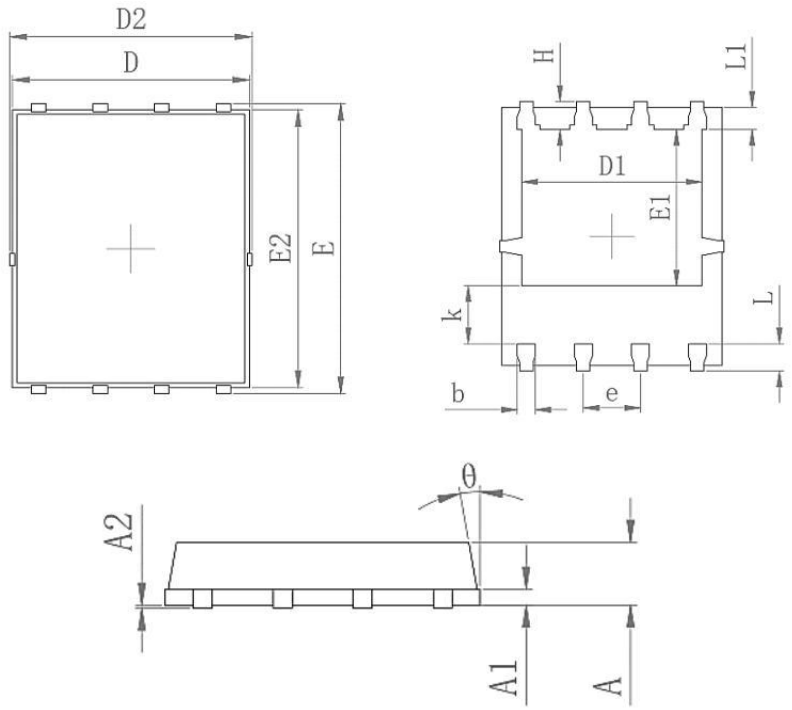


Figure.11: Maximum Effective Transient Thermal Impedance, Junction-to-Ambien

Package Mechanical Data-PDFN5X6-8L-XZT Single



Symbol	Common	
	mm	
	Mim	Max
A	0.90	1.10
A1	0.254 REF	
A2	0-0.05	
D	4.824	4.976
D1	3.910	4.110
D2	4.944	5.076
E	5.924	6.076
E1	3.375	3.575
E2	5.674	5.826
b	0.350	0.450
e	1.270	
L	0.534	0.686
L1	0.424	0.576
K	1.190	1.390
H	0.549	0.701
Φ	8°	12°

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
TAPING	PDFN5X6-8L		5000